

# 74AUP1GU04

## Low-power unbuffered inverter

Rev. 5 — 29 June 2012

Product data sheet

## 1. General description

The 74AUP1GU04 provides the single unbuffered inverting gate.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

## 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 5000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Multiple package options
- Specified from  $-40^{\circ}C$  to  $+85^{\circ}C$  and  $-40^{\circ}C$  to  $+125^{\circ}C$

## 3. Ordering information

Table 1. Ordering information

| Type number  | Package                           |        |                                                                                                                                    |          |
|--------------|-----------------------------------|--------|------------------------------------------------------------------------------------------------------------------------------------|----------|
|              | Temperature range                 | Name   | Description                                                                                                                        | Version  |
| 74AUP1GU04GW | $-40^{\circ}C$ to $+125^{\circ}C$ | TSSOP5 | plastic thin shrink small outline package; 5 leads; body width 1.25 mm                                                             | SOT353-1 |
| 74AUP1GU04GM | $-40^{\circ}C$ to $+125^{\circ}C$ | XSON6  | plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1.45 \times 0.5$ mm                            | SOT886   |
| 74AUP1GU04GF | $-40^{\circ}C$ to $+125^{\circ}C$ | XSON6  | plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1 \times 0.5$ mm                               | SOT891   |
| 74AUP1GU04GN | $-40^{\circ}C$ to $+125^{\circ}C$ | XSON6  | extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm                                  | SOT1115  |
| 74AUP1GU04GS | $-40^{\circ}C$ to $+125^{\circ}C$ | XSON6  | extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm                                  | SOT1202  |
| 74AUP1GU04GX | $-40^{\circ}C$ to $+125^{\circ}C$ | X2SON5 | X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm | SOT1226  |



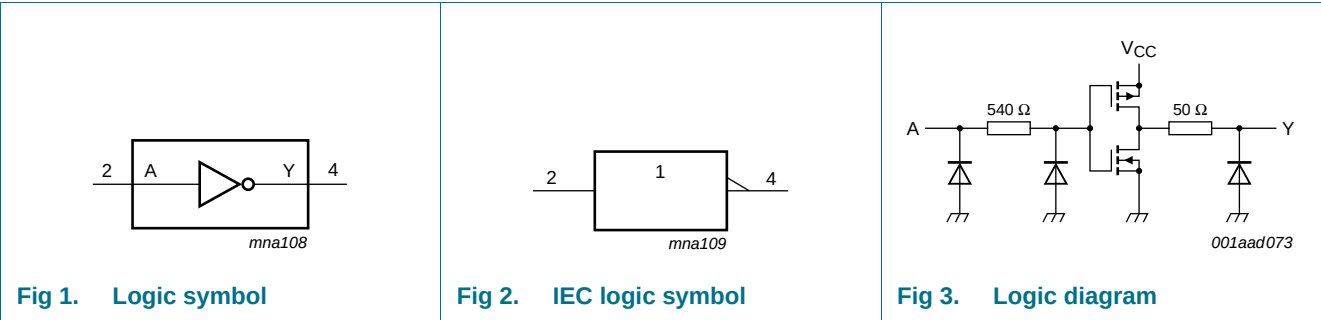
## 4. Marking

Table 2. Marking

| Type number  | Marking code <sup>[1]</sup> |
|--------------|-----------------------------|
| 74AUP1GU04GW | pD                          |
| 74AUP1GU04GM | pD                          |
| 74AUP1GU04GF | pD                          |
| 74AUP1GU04GN | pD                          |
| 74AUP1GU04GS | pD                          |
| 74AUP1GU04GX | pD                          |

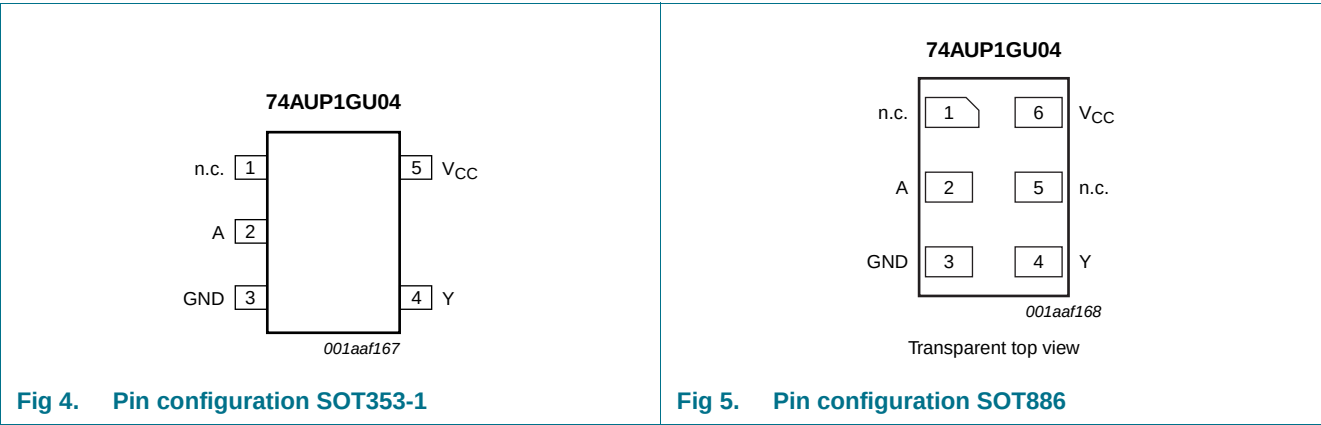
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

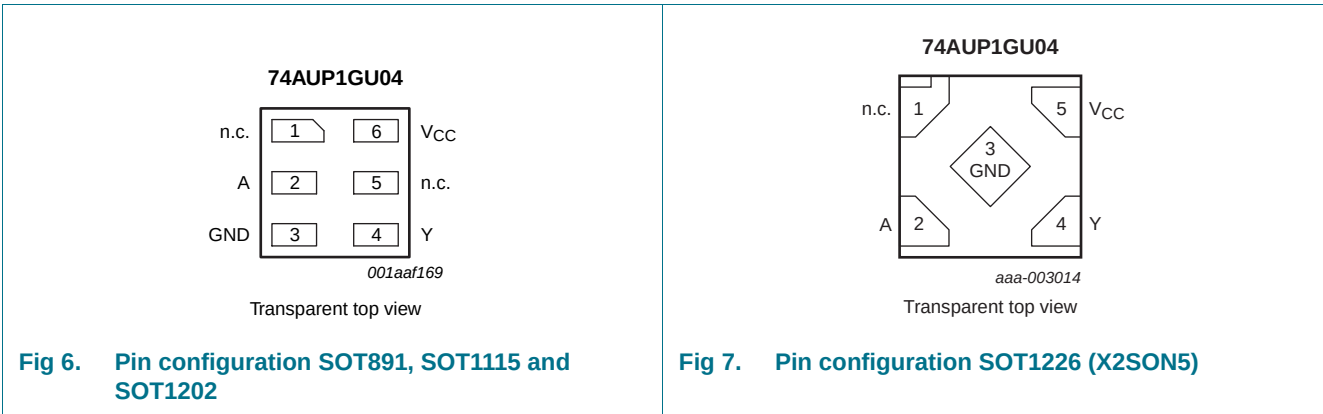
## 5. Functional diagram



## 6. Pinning information

### 6.1 Pinning





6.2 Pin description

Table 3. Pin description

| Symbol          | Pin               |       | Description    |
|-----------------|-------------------|-------|----------------|
|                 | TSSOP5 and X2SON5 | XSON6 |                |
| n.c.            | 1                 | 1     | not connected  |
| A               | 2                 | 2     | data input     |
| GND             | 3                 | 3     | ground (0 V)   |
| Y               | 4                 | 4     | data output    |
| n.c.            | -                 | 5     | not connected  |
| V <sub>CC</sub> | 5                 | 6     | supply voltage |

7. Functional description

Table 4. Function table<sup>[1]</sup>

| Input | Output |
|-------|--------|
| A     | Y      |
| L     | H      |
| H     | L      |

[1] H = HIGH voltage level; L = LOW voltage level.

## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                    | Min                 | Max            | Unit |
|-----------|-------------------------|-------------------------------|---------------------|----------------|------|
| $V_{CC}$  | supply voltage          |                               | -0.5                | +4.6           | V    |
| $I_{IK}$  | input clamping current  | $V_I < 0$ V                   | -50                 | -              | mA   |
| $V_I$     | input voltage           |                               | <sup>[1]</sup> -0.5 | +4.6           | V    |
| $I_{OK}$  | output clamping current | $V_O < 0$ V                   | -50                 | -              | mA   |
| $V_O$     | output voltage          |                               | <sup>[1]</sup> -0.5 | $V_{CC} + 0.5$ | V    |
| $I_O$     | output current          | $V_O = 0$ V to $V_{CC}$       | -                   | $\pm 20$       | mA   |
| $I_{CC}$  | supply current          |                               | -                   | +50            | mA   |
| $I_{GND}$ | ground current          |                               | -50                 | -              | mA   |
| $T_{stg}$ | storage temperature     |                               | -65                 | +150           | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to +125 °C | <sup>[2]</sup> -    | 250            | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP5 packages: above 87.5 °C the value of  $P_{tot}$  derates linearly with 4.0 mW/K.

For XSON6 and X2SON5 packages: above 118 °C the value of  $P_{tot}$  derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

**Table 6. Recommended operating conditions**

| Symbol              | Parameter                           | Conditions                | Min | Max      | Unit |
|---------------------|-------------------------------------|---------------------------|-----|----------|------|
| $V_{CC}$            | supply voltage                      |                           | 0.8 | 3.6      | V    |
| $V_I$               | input voltage                       |                           | 0   | 3.6      | V    |
| $V_O$               | output voltage                      |                           | 0   | $V_{CC}$ | V    |
| $T_{amb}$           | ambient temperature                 |                           | -40 | +125     | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 0.8$ V to 3.6 V | 0   | 200      | ns/V |

## 10. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                    | Parameter                 | Conditions                                                                                          | Min                    | Typ | Max                    | Unit |
|-------------------------------------------|---------------------------|-----------------------------------------------------------------------------------------------------|------------------------|-----|------------------------|------|
| <b>T<sub>amb</sub> = 25 °C</b>            |                           |                                                                                                     |                        |     |                        |      |
| V <sub>IH</sub>                           | HIGH-level input voltage  | V <sub>CC</sub> = 0.8 V to 3.6 V                                                                    | 0.75 × V <sub>CC</sub> | -   | -                      | V    |
| V <sub>IL</sub>                           | LOW-level input voltage   | V <sub>CC</sub> = 0.8 V to 3.6 V                                                                    | -                      | -   | 0.25 × V <sub>CC</sub> | V    |
| V <sub>OH</sub>                           | HIGH-level output voltage | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                           | V <sub>CC</sub> - 0.1  | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                   | 0.75 × V <sub>CC</sub> | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                   | 1.11                   | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                                  | 1.32                   | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                   | 2.05                   | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.9                    | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.72                   | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.6                    | -   | -                      | V    |
| V <sub>OL</sub>                           | LOW-level output voltage  | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                            | -                      | -   | 0.1                    | V    |
|                                           |                           | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                    | -                      | -   | 0.3 × V <sub>CC</sub>  | V    |
|                                           |                           | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                    | -                      | -   | 0.31                   | V    |
|                                           |                           | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                   | -                      | -   | 0.31                   | V    |
|                                           |                           | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.31                   | V    |
|                                           |                           | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.44                   | V    |
|                                           |                           | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.31                   | V    |
|                                           |                           | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.44                   | V    |
| I <sub>I</sub>                            | input leakage current     | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.1                   | µA   |
| I <sub>CC</sub>                           | supply current            | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 0.5                    | µA   |
| C <sub>I</sub>                            | input capacitance         | V <sub>CC</sub> = 0 V to 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub>                             | -                      | 1.5 | -                      | pF   |
| C <sub>O</sub>                            | output capacitance        | V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V                                                         | -                      | 1.8 | -                      | pF   |
| <b>T<sub>amb</sub> = -40 °C to +85 °C</b> |                           |                                                                                                     |                        |     |                        |      |
| V <sub>IH</sub>                           | HIGH-level input voltage  | V <sub>CC</sub> = 0.8 V to 3.6 V                                                                    | 0.75 × V <sub>CC</sub> | -   | -                      | V    |
| V <sub>IL</sub>                           | LOW-level input voltage   | V <sub>CC</sub> = 0.8 V to 3.6 V                                                                    | -                      | -   | 0.25 × V <sub>CC</sub> | V    |
| V <sub>OH</sub>                           | HIGH-level output voltage | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                           | V <sub>CC</sub> - 0.1  | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                   | 0.7 × V <sub>CC</sub>  | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                   | 1.03                   | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                                  | 1.30                   | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.97                   | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.85                   | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.67                   | -   | -                      | V    |
|                                           |                           | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.55                   | -   | -                      | V    |

**Table 7.** Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                 | Conditions                                                                                          | Min                    | Typ | Max                    | Unit |
|--------------------------------------------|---------------------------|-----------------------------------------------------------------------------------------------------|------------------------|-----|------------------------|------|
| V <sub>OL</sub>                            | LOW-level output voltage  | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                            | -                      | -   | 0.1                    | V    |
|                                            |                           | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                    | -                      | -   | 0.3 × V <sub>CC</sub>  | V    |
|                                            |                           | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                    | -                      | -   | 0.37                   | V    |
|                                            |                           | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                   | -                      | -   | 0.35                   | V    |
|                                            |                           | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.33                   | V    |
|                                            |                           | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.45                   | V    |
|                                            |                           | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.33                   | V    |
|                                            |                           | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.45                   | V    |
| I <sub>I</sub>                             | input leakage current     | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.5                   | µA   |
| I <sub>CC</sub>                            | supply current            | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 0.9                    | µA   |
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                           |                                                                                                     |                        |     |                        |      |
| V <sub>IH</sub>                            | HIGH-level input voltage  | V <sub>CC</sub> = 0.8 V to 3.6 V                                                                    | 0.75 × V <sub>CC</sub> | -   | -                      | V    |
| V <sub>IL</sub>                            | LOW-level input voltage   | V <sub>CC</sub> = 0.8 V to 3.6 V                                                                    | -                      | -   | 0.25 × V <sub>CC</sub> | V    |
| V <sub>OH</sub>                            | HIGH-level output voltage | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                           | V <sub>CC</sub> - 0.11 | -   | -                      | V    |
|                                            |                           | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                   | 0.6 × V <sub>CC</sub>  | -   | -                      | V    |
|                                            |                           | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                   | 0.93                   | -   | -                      | V    |
|                                            |                           | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                                  | 1.17                   | -   | -                      | V    |
|                                            |                           | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.77                   | -   | -                      | V    |
|                                            |                           | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.67                   | -   | -                      | V    |
|                                            |                           | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.40                   | -   | -                      | V    |
|                                            |                           | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.30                   | -   | -                      | V    |
| V <sub>OL</sub>                            | LOW-level output voltage  | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                            | -                      | -   | 0.11                   | V    |
|                                            |                           | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                    | -                      | -   | 0.33 × V <sub>CC</sub> | V    |
|                                            |                           | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                    | -                      | -   | 0.41                   | V    |
|                                            |                           | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                   | -                      | -   | 0.39                   | V    |
|                                            |                           | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.36                   | V    |
|                                            |                           | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.50                   | V    |
|                                            |                           | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.36                   | V    |
|                                            |                           | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.50                   | V    |
| I <sub>I</sub>                             | input leakage current     | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.75                  | µA   |
| I <sub>CC</sub>                            | supply current            | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 1.4                    | µA   |

## 11. Dynamic characteristics

**Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#)

| Symbol                 | Parameter         | Conditions                           | 25 °C               |                    |      | –40 °C to +125 °C |                |                 | Unit |
|------------------------|-------------------|--------------------------------------|---------------------|--------------------|------|-------------------|----------------|-----------------|------|
|                        |                   |                                      | Min                 | Typ <sup>[1]</sup> | Max  | Min               | Max<br>(85 °C) | Max<br>(125 °C) |      |
| C <sub>L</sub> = 5 pF  |                   |                                      |                     |                    |      |                   |                |                 |      |
| t <sub>pd</sub>        | propagation delay | A to Y; see <a href="#">Figure 8</a> | <a href="#">[2]</a> |                    |      |                   |                |                 |      |
|                        |                   | V <sub>CC</sub> = 0.8 V              | -                   | 6.2                | -    | -                 | -              | -               | ns   |
|                        |                   | V <sub>CC</sub> = 1.1 V to 1.3 V     | 0.9                 | 2.3                | 4.4  | 0.9               | 4.8            | 5.3             | ns   |
|                        |                   | V <sub>CC</sub> = 1.4 V to 1.6 V     | 0.7                 | 1.7                | 3.1  | 0.6               | 3.4            | 3.8             | ns   |
|                        |                   | V <sub>CC</sub> = 1.65 V to 1.95 V   | 0.5                 | 1.4                | 2.6  | 0.5               | 2.9            | 3.2             | ns   |
|                        |                   | V <sub>CC</sub> = 2.3 V to 2.7 V     | 0.4                 | 1.1                | 2.0  | 0.4               | 2.3            | 2.6             | ns   |
|                        |                   | V <sub>CC</sub> = 3.0 V to 3.6 V     | 0.3                 | 1.0                | 1.8  | 0.3               | 2.1            | 2.4             | ns   |
| C <sub>L</sub> = 10 pF |                   |                                      |                     |                    |      |                   |                |                 |      |
| t <sub>pd</sub>        | propagation delay | A to Y; see <a href="#">Figure 8</a> | <a href="#">[2]</a> |                    |      |                   |                |                 |      |
|                        |                   | V <sub>CC</sub> = 0.8 V              | -                   | 9.6                | -    | -                 | -              | -               | ns   |
|                        |                   | V <sub>CC</sub> = 1.1 V to 1.3 V     | 1.2                 | 3.1                | 6.1  | 1.2               | 6.8            | 7.5             | ns   |
|                        |                   | V <sub>CC</sub> = 1.4 V to 1.6 V     | 1.0                 | 2.3                | 4.0  | 0.9               | 4.6            | 5.1             | ns   |
|                        |                   | V <sub>CC</sub> = 1.65 V to 1.95 V   | 0.8                 | 1.9                | 3.3  | 0.7               | 3.8            | 4.2             | ns   |
|                        |                   | V <sub>CC</sub> = 2.3 V to 2.7 V     | 0.6                 | 1.5                | 2.7  | 0.6               | 3.1            | 3.5             | ns   |
|                        |                   | V <sub>CC</sub> = 3.0 V to 3.6 V     | 0.5                 | 1.3                | 2.4  | 0.5               | 2.7            | 3.0             | ns   |
| C <sub>L</sub> = 15 pF |                   |                                      |                     |                    |      |                   |                |                 |      |
| t <sub>pd</sub>        | propagation delay | A to Y; see <a href="#">Figure 8</a> | <a href="#">[2]</a> |                    |      |                   |                |                 |      |
|                        |                   | V <sub>CC</sub> = 0.8 V              | -                   | 13.0               | -    | -                 | -              | -               | ns   |
|                        |                   | V <sub>CC</sub> = 1.1 V to 1.3 V     | 1.6                 | 3.8                | 7.9  | 1.4               | 8.8            | 9.7             | ns   |
|                        |                   | V <sub>CC</sub> = 1.4 V to 1.6 V     | 1.3                 | 2.8                | 4.9  | 1.1               | 5.7            | 6.3             | ns   |
|                        |                   | V <sub>CC</sub> = 1.65 V to 1.95 V   | 1.0                 | 2.3                | 4.0  | 0.9               | 4.7            | 5.2             | ns   |
|                        |                   | V <sub>CC</sub> = 2.3 V to 2.7 V     | 0.8                 | 1.9                | 3.2  | 0.8               | 3.7            | 4.1             | ns   |
|                        |                   | V <sub>CC</sub> = 3.0 V to 3.6 V     | 0.7                 | 1.6                | 2.9  | 0.7               | 3.3            | 3.7             | ns   |
| C <sub>L</sub> = 30 pF |                   |                                      |                     |                    |      |                   |                |                 |      |
| t <sub>pd</sub>        | propagation delay | A to Y; see <a href="#">Figure 8</a> | <a href="#">[2]</a> |                    |      |                   |                |                 |      |
|                        |                   | V <sub>CC</sub> = 0.8 V              | -                   | 23.2               | -    | -                 | -              | -               | -    |
|                        |                   | V <sub>CC</sub> = 1.1 V to 1.3 V     | 2.4                 | 6.0                | 13.1 | 2.2               | 14.8           | 16.3            | ns   |
|                        |                   | V <sub>CC</sub> = 1.4 V to 1.6 V     | 2.0                 | 4.2                | 7.6  | 1.8               | 9.0            | 9.9             | ns   |
|                        |                   | V <sub>CC</sub> = 1.65 V to 1.95 V   | 1.7                 | 3.6                | 6.1  | 1.5               | 7.2            | 8.0             | ns   |
|                        |                   | V <sub>CC</sub> = 2.3 V to 2.7 V     | 1.4                 | 2.9                | 4.8  | 1.3               | 5.7            | 6.3             | ns   |
|                        |                   | V <sub>CC</sub> = 3.0 V to 3.6 V     | 1.2                 | 2.5                | 4.3  | 1.1               | 5.1            | 5.7             | ns   |

**Table 8. Dynamic characteristics ...continued**

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#)

| Symbol | Parameter | Conditions | 25 °C |                    |     | –40 °C to +125 °C |             |              | Unit |
|--------|-----------|------------|-------|--------------------|-----|-------------------|-------------|--------------|------|
|        |           |            | Min   | Typ <sup>[1]</sup> | Max | Min               | Max (85 °C) | Max (125 °C) |      |

**$C_L = 5 \text{ pF}, 10 \text{ pF}, 15 \text{ pF}$  and  $30 \text{ pF}$**

|          |                               |                                                                 |   |     |   |   |   |   |    |
|----------|-------------------------------|-----------------------------------------------------------------|---|-----|---|---|---|---|----|
| $C_{PD}$ | power dissipation capacitance | $f = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ <sup>[3]</sup> |   |     |   |   |   |   |    |
|          |                               | $V_{CC} = 0.8 \text{ V}$                                        | - | 1.2 | - | - | - | - | pF |
|          |                               | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$                      | - | 1.1 | - | - | - | - | pF |
|          |                               | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$                      | - | 1.2 | - | - | - | - | pF |
|          |                               | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$                    | - | 1.4 | - | - | - | - | pF |
|          |                               | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$                      | - | 2.8 | - | - | - | - | pF |
|          |                               | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$                      | - | 4.4 | - | - | - | - | pF |

[1] All typical values are measured at nominal  $V_{CC}$ .

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

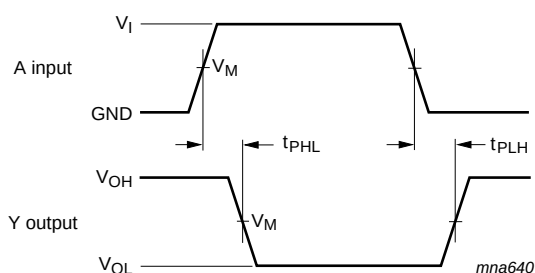
$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

## 12. Waveforms



Measurement points are given in [Table 9](#).

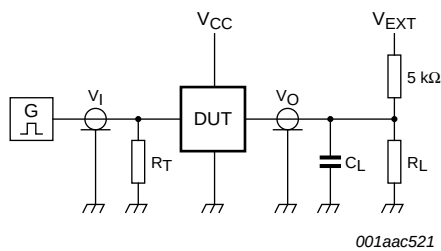
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage drop that occur with the output load.

**Fig 8. The data input (A) to output (Y) propagation delays**

**Table 9. Measurement points**

| Supply voltage | Output              | Input               |          |                       |
|----------------|---------------------|---------------------|----------|-----------------------|
| $V_{CC}$       | $V_M$               | $V_M$               | $V_I$    | $t_r = t_f$           |
| 0.8 V to 3.6 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ | $V_{CC}$ | $\leq 3.0 \text{ ns}$ |





Test data is given in [Table 10](#).  
Definitions for test circuit:  
 $R_L$  = Load resistance.  
 $C_L$  = Load capacitance including jig and probe capacitance.  
 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.  
 $V_{EXT}$  = External voltage for measuring switching times.

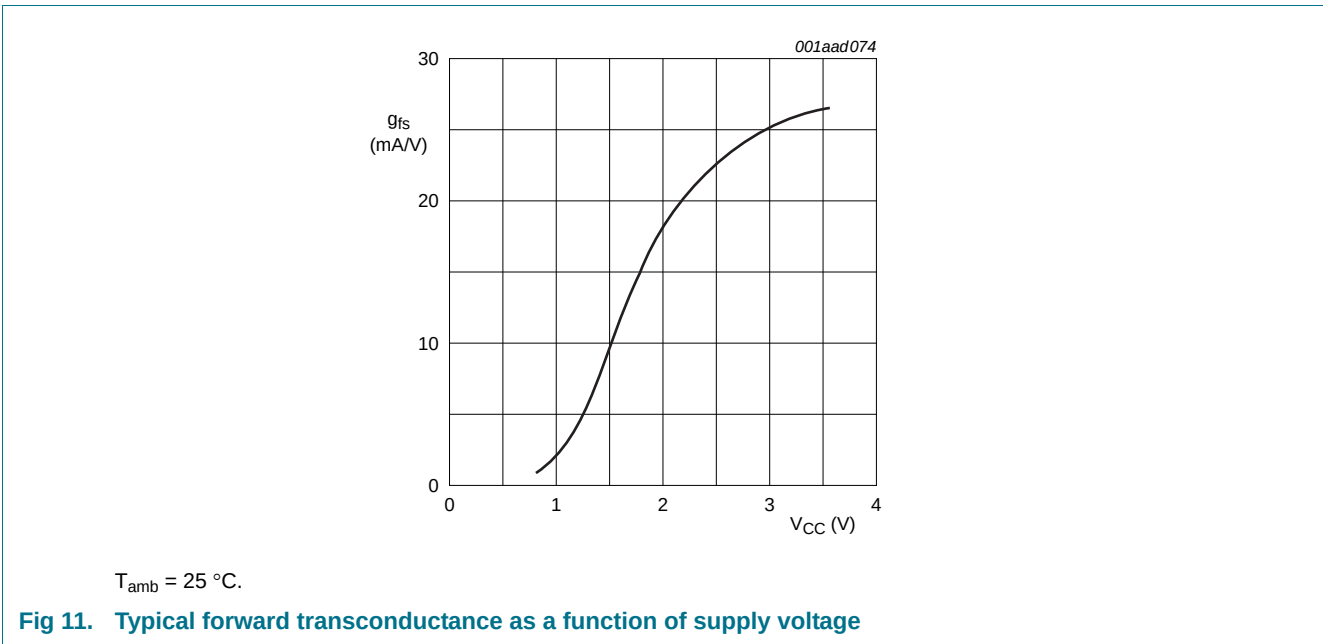
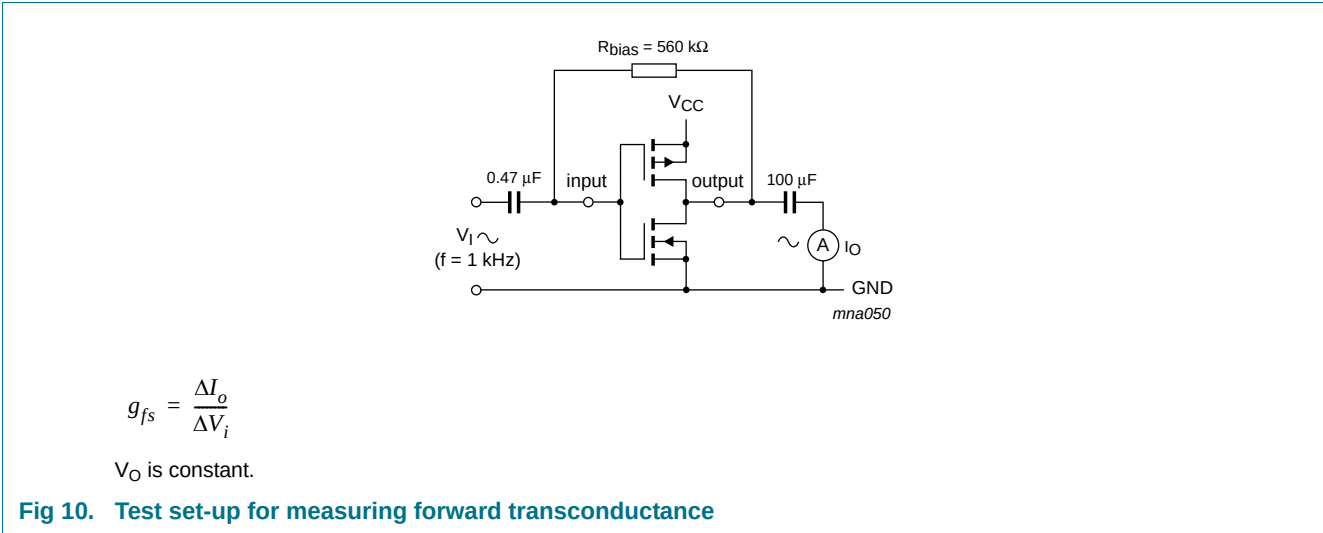
Fig 9. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage | Load                         |              | $V_{EXT}$             |                       |                       |
|----------------|------------------------------|--------------|-----------------------|-----------------------|-----------------------|
| $V_{CC}$       | $C_L$                        | $R_L$ [1]    | $t_{PLH}$ , $t_{PHL}$ | $t_{PZH}$ , $t_{PHZ}$ | $t_{PZL}$ , $t_{PLZ}$ |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ | open                  | GND                   | $2 \times V_{CC}$     |

[1] For measuring enable and disable times  $R_L = 5 \text{ k}\Omega$ , for measuring propagation delays, setup and hold times and pulse width  $R_L = 1 \text{ M}\Omega$ .

13. Additional characteristics

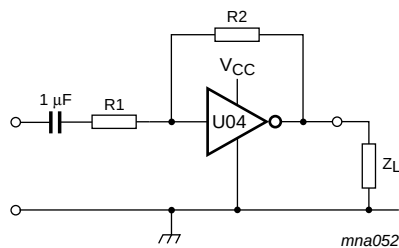


## 14. Application information

Some applications for the 74AUP1GU04 are:

- Linear amplifier (see [Figure 12](#))
- Crystal oscillator (see [Figure 13](#)).

**Remark:** All values given are typical values unless otherwise specified.



$Z_L > 10 \text{ k}\Omega$ .

$R1 \geq 3 \text{ k}\Omega$ .

$R2 \leq 1 \text{ M}\Omega$ .

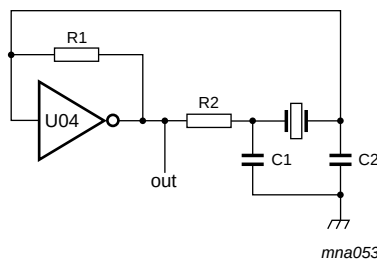
Open loop gain:  $G_{OL} = 20$ .

$$\text{Voltage amplification: } A_V = -\frac{G_{OL}}{1 + \frac{R1}{R2}(1 + G_{OL})}$$

$V_{o(p-p)} = V_{CC} - 1.5 \text{ V}$  centered at  $0.5 \times V_{CC}$ .

Unity gain bandwidth product is 5 MHz.

**Fig 12. Linear amplifier application**



$C1 = 47 \text{ pF}$ .

$C2 = 22 \text{ pF}$ .

$R1 = 1 \text{ M}\Omega$  to  $10 \text{ M}\Omega$ .

$R2$  optimum value depends on the frequency and required stability against changes in  $V_{CC}$  or average minimum  $I_{CC}$  ( $I_{CC} = 2 \text{ mA}$  at  $V_{CC} = 3.3 \text{ V}$  and  $f = 10 \text{ MHz}$ ).

**Fig 13. Crystal oscillator application**

15. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mmSOT353-1

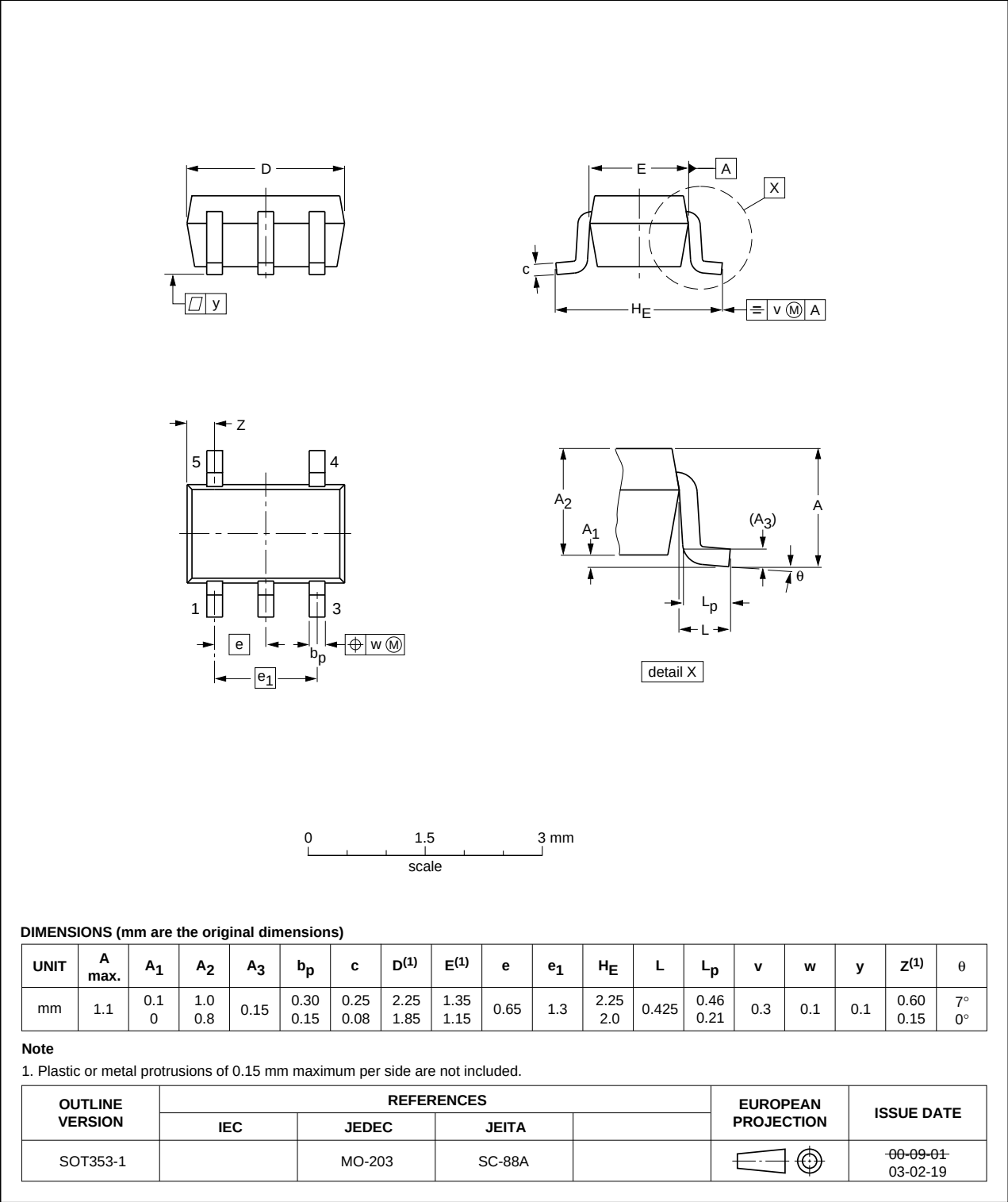


Fig 14. Package outline SOT353-1 (TSSOP5)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

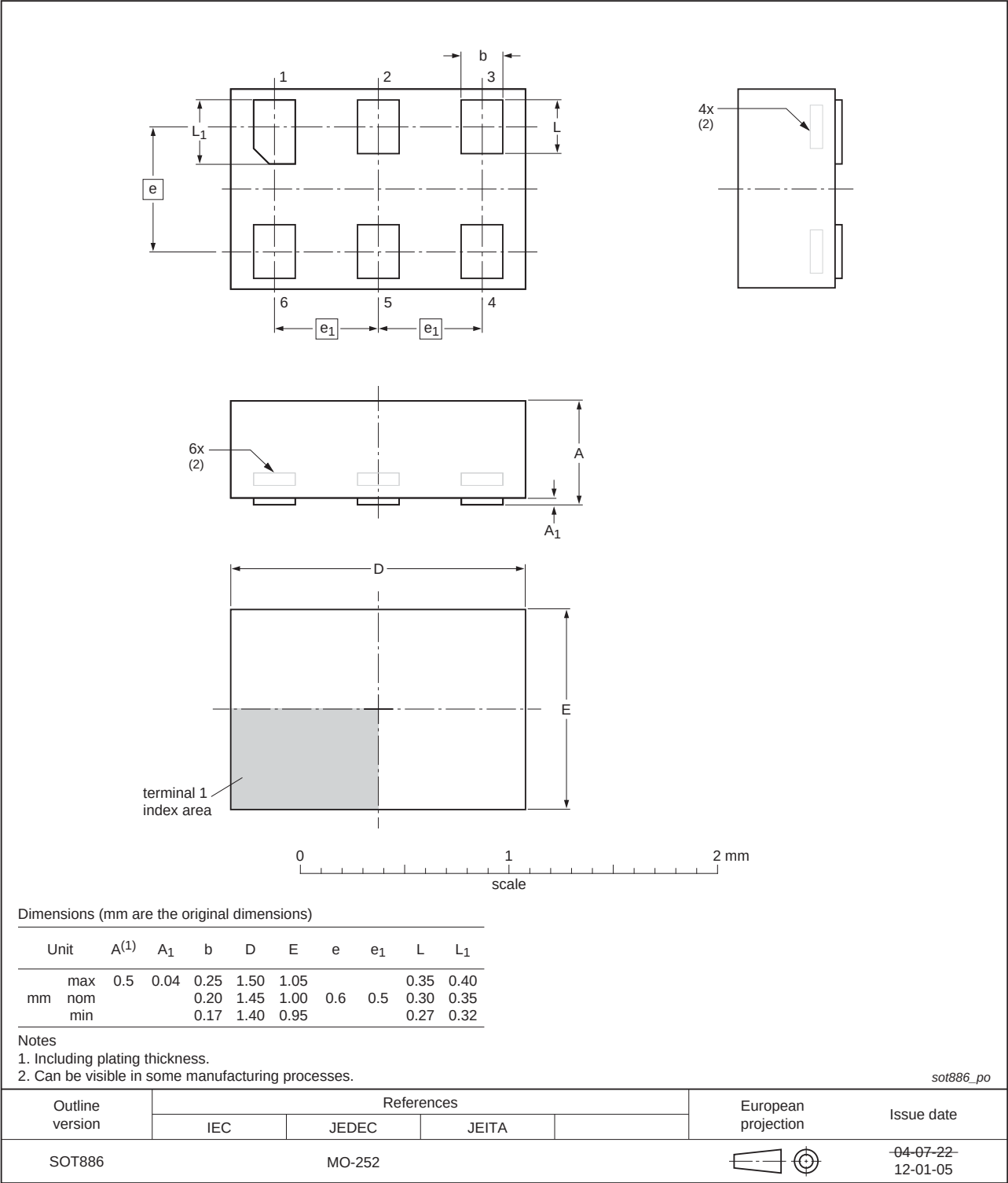


Fig 15. Package outline SOT886 (XSON6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891

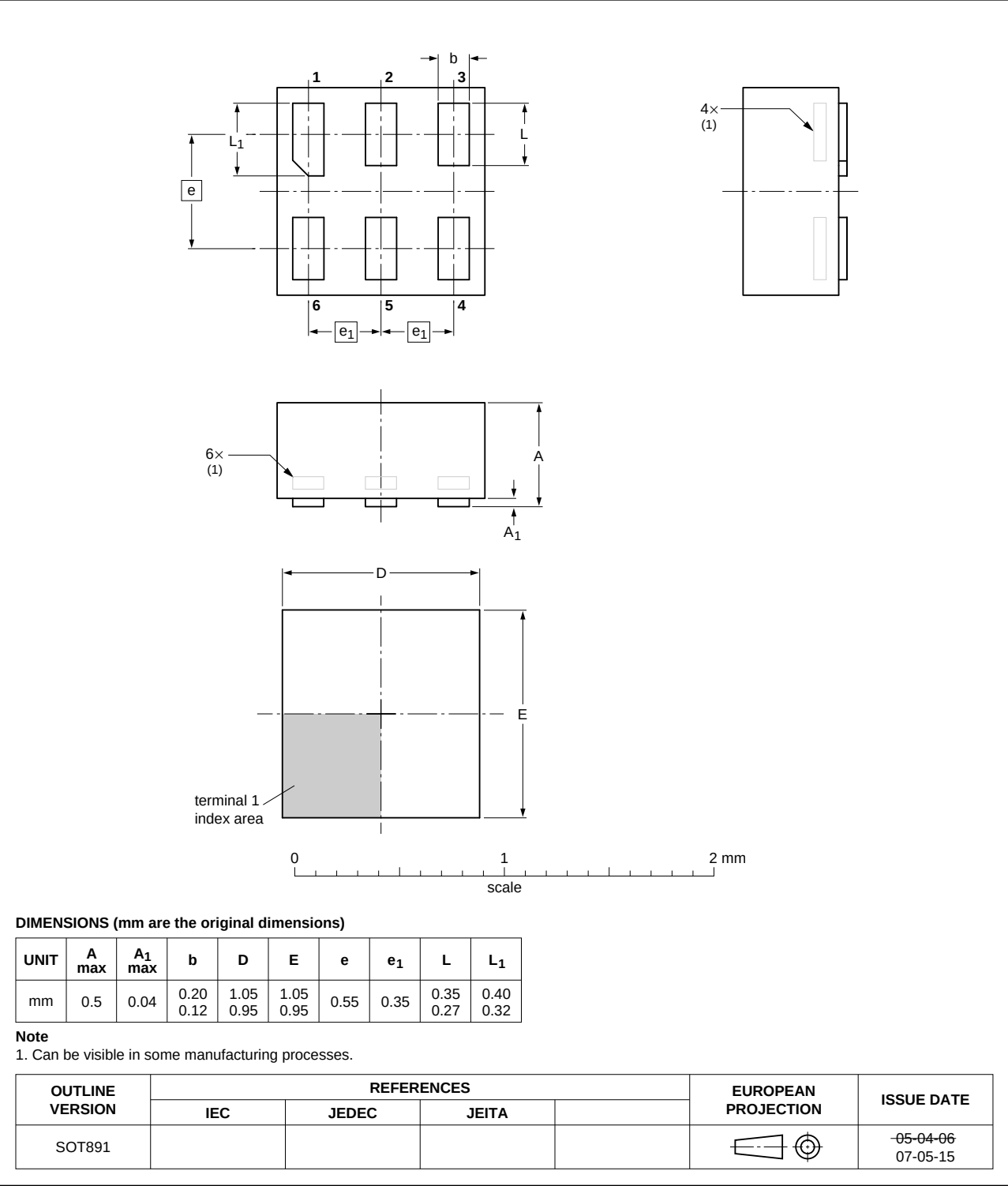
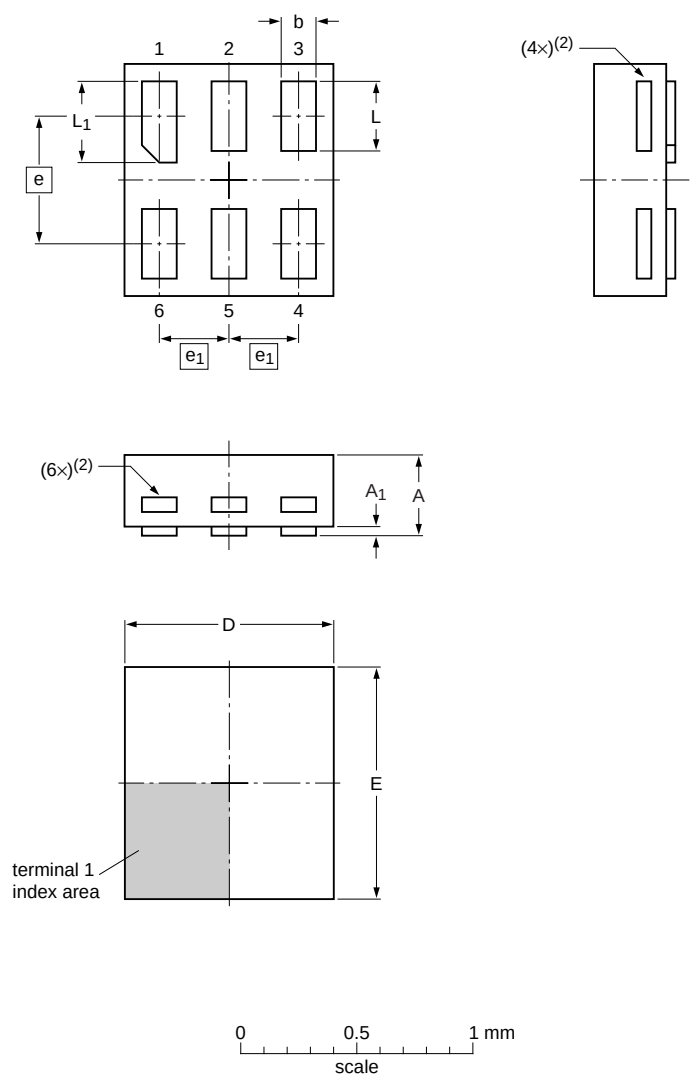


Fig 16. Package outline SOT891 (XSON6)

XSON6: extremely thin small outline package; no leads;  
6 terminals; body 0.9 x 1.0 x 0.35 mm

SOT1115



Dimensions

| Unit | A <sup>(1)</sup> | A <sub>1</sub> | b    | D    | E    | e    | e <sub>1</sub> | L    | L <sub>1</sub> |
|------|------------------|----------------|------|------|------|------|----------------|------|----------------|
| mm   | max              | 0.35           | 0.04 | 0.20 | 0.95 | 1.05 |                | 0.35 | 0.40           |
|      | nom              |                |      | 0.15 | 0.90 | 1.00 | 0.55           | 0.30 | 0.35           |
|      | min              |                |      | 0.12 | 0.85 | 0.95 |                | 0.27 | 0.32           |

Note

1. Including plating thickness.

2. Visible depending upon used manufacturing technology.

sot1115\_po

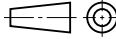
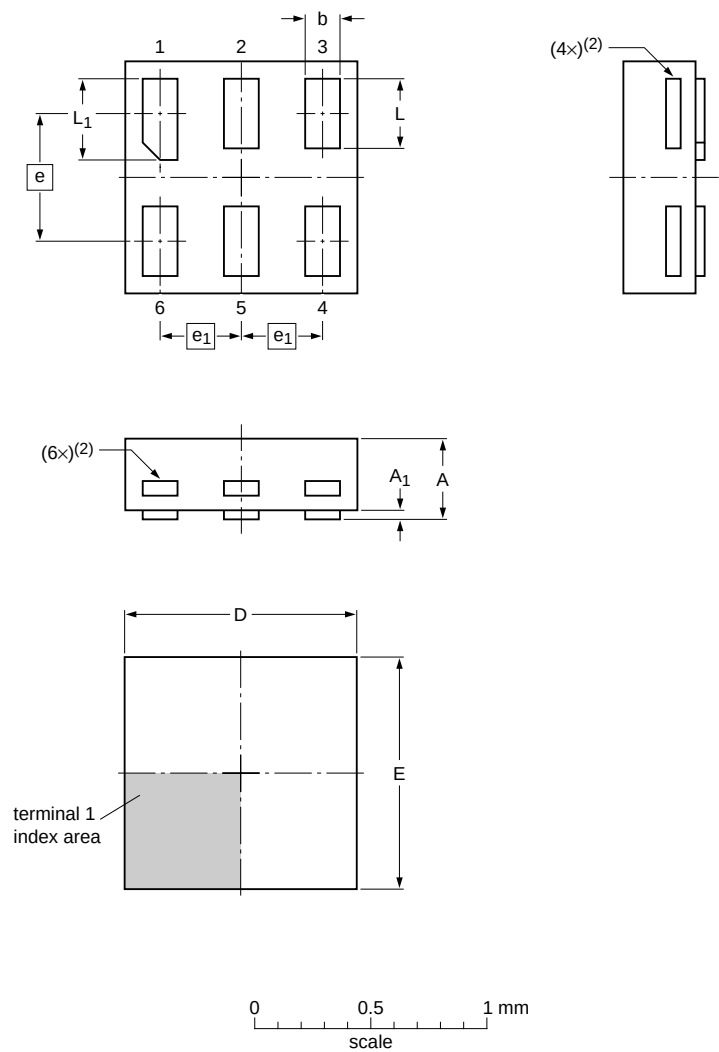
| Outline version | References |       |       |  | European projection                                                                   | Issue date                      |
|-----------------|------------|-------|-------|--|---------------------------------------------------------------------------------------|---------------------------------|
|                 | IEC        | JEDEC | JEITA |  |                                                                                       |                                 |
| SOT1115         |            |       |       |  |  | <del>10-04-02</del><br>10-04-07 |

Fig 17. Package outline SOT1115 (XSON6)

XSON6: extremely thin small outline package; no leads;  
6 terminals; body 1.0 x 1.0 x 0.35 mm

SOT1202



Dimensions

| Unit | A <sup>(1)</sup> | A <sub>1</sub> | b    | D    | E    | e    | e <sub>1</sub> | L    | L <sub>1</sub> |
|------|------------------|----------------|------|------|------|------|----------------|------|----------------|
| mm   | max              | 0.35           | 0.04 | 0.20 | 1.05 | 1.05 |                | 0.35 | 0.40           |
|      | nom              |                |      | 0.15 | 1.00 | 1.00 | 0.55           | 0.30 | 0.35           |
|      | min              |                |      | 0.12 | 0.95 | 0.95 |                | 0.27 | 0.32           |

Note

- 1. Including plating thickness.
- 2. Visible depending upon used manufacturing technology.

sot1202\_po

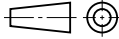
| Outline version | References |       |       |  | European projection                                                                   | Issue date                      |
|-----------------|------------|-------|-------|--|---------------------------------------------------------------------------------------|---------------------------------|
|                 | IEC        | JEDEC | JEITA |  |                                                                                       |                                 |
| SOT1202         |            |       |       |  |  | <del>10-04-02</del><br>10-04-06 |

Fig 18. Package outline SOT1202 (XSON6)



X2SON5: plastic thermal enhanced extremely thin small outline package; no leads;  
5 terminals; body 0.8 x 0.8 x 0.35 mm

SOT1226

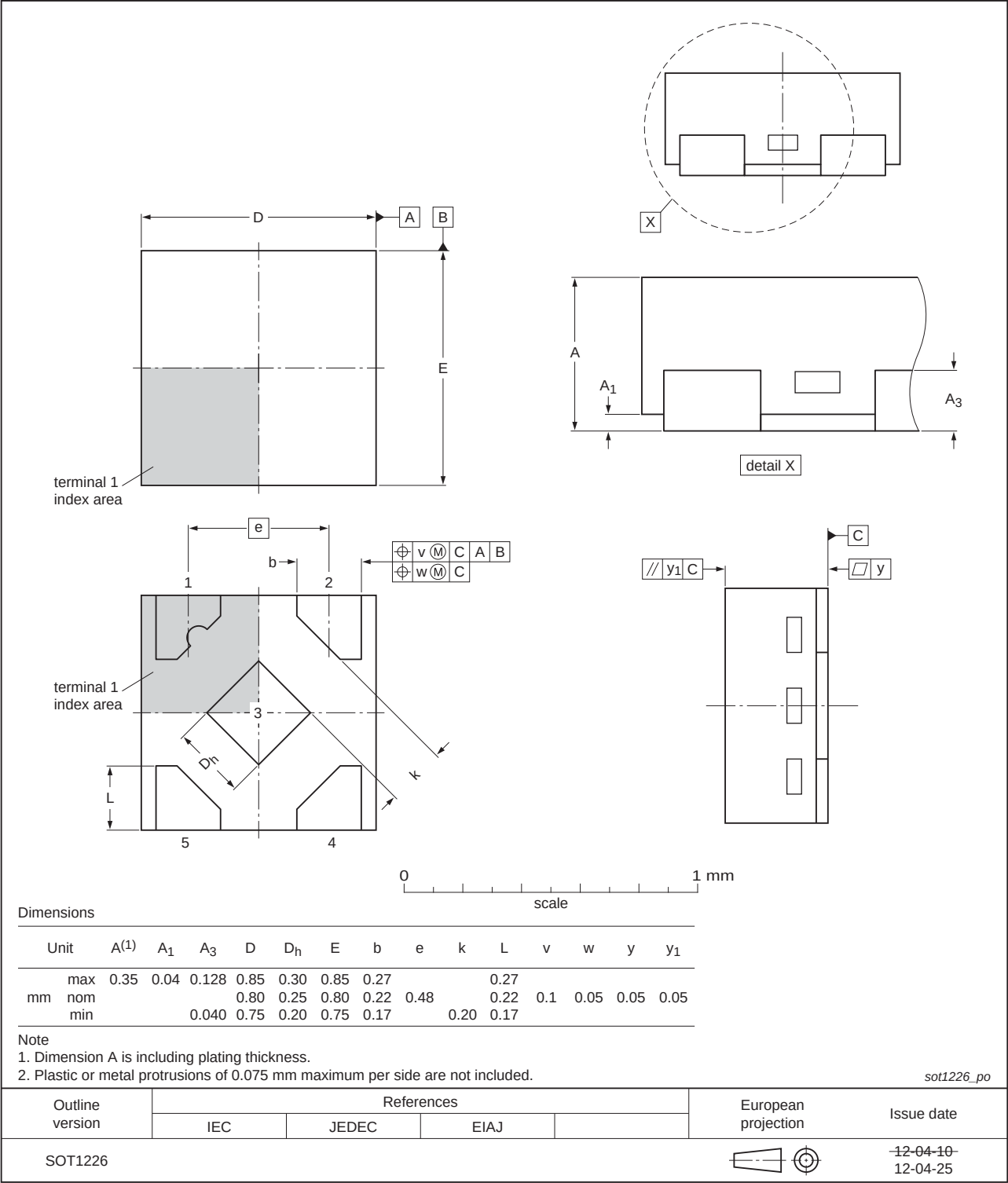


Fig 19. Package outline SOT1226 (X2SON5)

## 16. Abbreviations

Table 11. Abbreviations

| Acronym | Description             |
|---------|-------------------------|
| CDM     | Charged Device Model    |
| DUT     | Device Under Test       |
| ESD     | ElectroStatic Discharge |
| HBM     | Human Body Model        |
| MM      | Machine Model           |

## 17. Revision history

Table 12. Revision history

| Document ID    | Release date                                                                                                                                                             | Data sheet status  | Change notice | Supersedes     |
|----------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|---------------|----------------|
| 74AUP1GU04 v.5 | 20120629                                                                                                                                                                 | Product data sheet | -             | 74AUP1GU04 v.4 |
| Modifications: | <ul style="list-style-type: none"><li>Added type number 74AUP1GU04GX (SOT1226)</li><li>Package outline drawing of SOT886 (<a href="#">Figure 15</a>) modified.</li></ul> |                    |               |                |
| 74AUP1GU04 v.4 | 20111116                                                                                                                                                                 | Product data sheet | -             | 74AUP1GU04 v.3 |
| Modifications: | <ul style="list-style-type: none"><li>Legal pages updated.</li><li>Package outline drawing SOT363 replaced by SOT353-1.</li></ul>                                        |                    |               |                |
| 74AUP1GU04 v.3 | 20100721                                                                                                                                                                 | Product data sheet | -             | 74AUP1GU04 v.2 |
| 74AUP1GU04 v.2 | 20060803                                                                                                                                                                 | Product data sheet | -             | 74AUP1GU04 v.1 |
| 74AUP1GU04 v.1 | 20050810                                                                                                                                                                 | Product data sheet | -             | -              |

## 18. Legal information

### 18.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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